SanRex

THYRISTOR / DIODE (ISOLATED TYPE)

PK(PD)160FG40/80/120/160

 $I_{T(AV)} = 160A$, $V_{RRM} = 400 - 1600V$

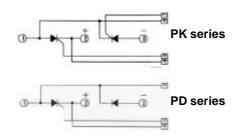
SanRex Thyristor/Thyristor modules (**PK series**), Thyristor/Diode modules (**PD series**) are designed for general purpose high voltage applications such as motor controls, temperature controls, lighting controls and UPS.

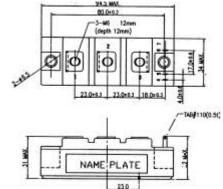
Features

- * Glass-passivated junctions Features
- * High Surge Current
- * Low loss $(V_{TM}=1.5V)$

Typical Applications

- * Motor Controls
- * Temperature Controls
- * Lighting Controls





< Maximum Ratings >

(Tj = 25°C unless otherwise noted)

Symbol	Item		Ratings					
			PK160FG40	PK160FG80	PK160FG12	0 PK160FG160	Unit	
V_{RRM}	Repetitive Pe	eak Reverse Voltage	400	800	1200	1600	V	
V_{RSM}	Non-Repetiti	ve Peak Reverse Voltage	480	960	1300	1700	V	
V_{DRM}	Repetitive Pe	eak Off-state Voltage	400	800	1200	1600	V	
I _{T(AV)}	Average On-	state Current	T _C = 84°C			160	Α	
I _{T(RMS)}	R.M.S. On-s	tate Current	T _C = 84°C			251		
I _{TSM}	Surge On-sta	ate Current	1/2 cycle, 50Hz/60Hz, Peak value, Non-repetitive			5000/5400		
l²t	I2t (for fusin	g)	Value for one cycle surge current			125000		
P _{GM}	Peak Gate P	ower Dissipation				10	W	
P _{G(AV)}	Average Gat	e Power Dissipation				3	W	
I _{FGM}	Peak Gate C	Current				3	Α	
V_{FGM}	Peak Gate V	oltage (Forward)				10	V	
V_{RGM}	Peak Gate V	oltage (Reverse)				5		
di/dt	Critical Rate	of Rise of On-state Current	I _G =100mA, V _D =1/2V _{DRM} , dig/dt=0.1A/Fs			200		
V _{ISO}	Isolation Bre	akdown Voltage	A.C. 1 minute			2500		
Tj	Operating Ju	inction Temperature				-40 to +125		
T _{stg}	Storage Tem	perature				-40 to +125	°C	
-	Mounting	Mounting M6	Recommende	d Value 2.5 to 3.9)	4.7		
	Torque	Terminals M6	Recommended Value 2.5 to 3.9			4.7		
	Mass	•	Typical Value			210		

< Electrical Characteristics >

(Tj = 25°C unless otherwise noted)

Symbol	Item	Conditions	Ratings			Unit
Symbol	петі	Conditions	Min.	Тур.	Max.	Unit
I _{DRM}	Repetitive Peak Off-state Current	$T_j = 125$ °C, $V_D = V_{DRM}$			35	mΑ
I _{RRM}	Repetitive Peak Reverse Current	$T_j = 125$ °C, $V_R = V_{RRM}$			35	mΑ
V_{TM}	Peak On-State Voltage	I _T = 480A			1.5	V
I_{GT}	Gate Trigger Current	VD=6V, IT=1A			100	mΑ
V _{GT}	Gate Trigger Voltage	VD=6V, IT=1A			3	V
V _{G D}	Non-Trigger Gate Voltage	$Tj = 125^{\circ}C, V_D=1/2V_{DRM}$	0.25			V
dv/dt	Critical Rate of Rise of Off-state Voltage	$Tj = 125^{\circ}C, V_D = 2/3V_{DRM}$	500			V/Fs
Rth(j-c)	Thermal Resistance	Junction to case			0.18	°C/W